TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXR162501FT

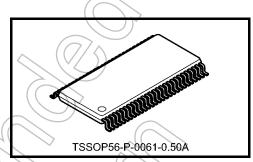
Low-Voltage 18-Bit Universal Bus Transceiver with 3.6-V Tolerant Inputs and Outputs

The TC74VCXR162501FT is a high-performance CMOS 18-bit universal bus transceiver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to $3.6\ V.$

Data flow $\underline{\text{in eac}}$ h direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CKAB and CKBA) inputs.

For A-to-B data flow, the device operates in the transparent mode when LEAB is high. When LEAB is low, the A data is latched if CKAB is held at a high or low logic level. If LEAB is



Weight: 0.25 g (typ.)

low, the A bus data is stored in the latch/flip-flop on the low-to-high transition of CKAB.

Data flow for B to A is similar to that of A to B but uses OEBA, LEBA, and CKBA.

When the OE input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

The $26-\Omega$ series resistor helps reducing output overshoot and undershoot without external resistor. All inputs are equipped with protection circuits against static discharge.

Features (Note)

- 26-Ω series resistors on outputs
- Low-voltage operation: V_{CC} = 1.8 to 3.6 V
- High-speed operation: $t_{pd} = 3.8 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$

 $: t_{pd} = 4.9 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$

 $t_{pd} = 9.8 \text{ ns (max) (VCC} = 1.8 \text{ V)}$

• Output current: $I_{OH}/I_{OL} = \pm 12 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$

 $: I_{OH}/I_{OL} = \pm 8 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

 $: I_{OH}/I_{OL} = \pm 4 \text{ mA (min) (V}_{CC} = 1.8 \text{ V)}$

- Latch-up performance: -300 mA
- ESD performance: Machine model ≥ ±200 V

Human body model≥±2000 V

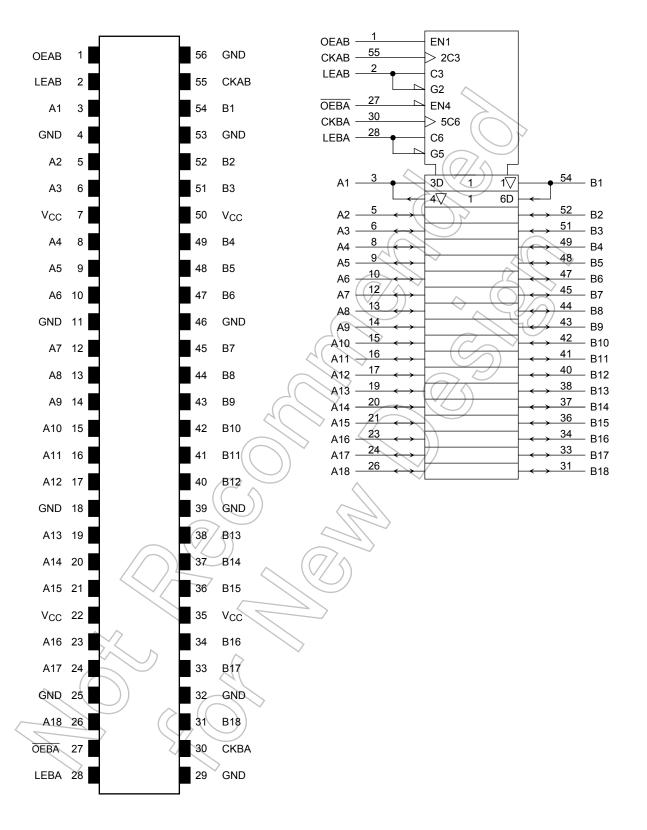
- Package: TSSOP
- Bidirectional interface between 2.5 V and 3.3 V signals.
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input level fixed by means of pull-up or pull-down resistors.

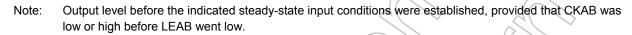
Pin Assignment (top view)

IEC Logic Symbol



Truth Table (A bus → B bus)

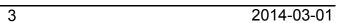
	Inputs						
OEAB	LEAB	CKAB	Α	В			
L	Х	Х	Х	Z			
Н	Н	Х	L	L			
Н	Н	Х	Н	Н			
Н	L		L	L			
Н	L		Н	Н			
Н	L	Н	Х	В0			
				(Note)			
Н	L	L	Х	В0			
				(Note)			



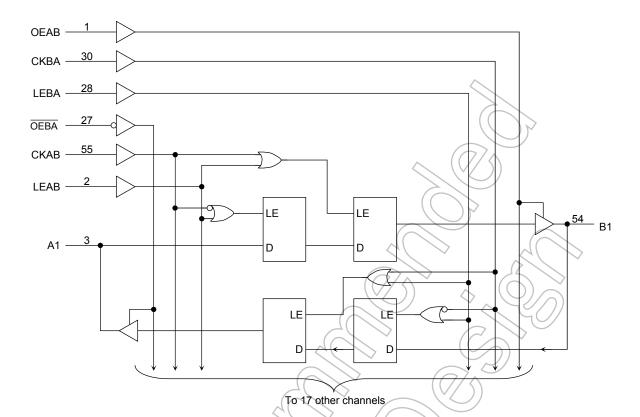
Truth Table (B bus \rightarrow A bus)

	Inputs						
OEBA	LEBA	CKBA	В	A			
Н	Х	Х	Х	Z			
L	Н	X	L	7(7)			
L	Н	Х	н 🗸	H			
L	L			\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\			
L	L		H)) н			
L	L	Н	X	A0 _			
			((5))	(Note)			
L	L	L	X	A0			
		_ ((//		(Note)			

Note: Output level before the indicated steady-state input conditions were established, provided that CKBA was low or high before LEBA went low.



System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	(V _{CC})	-0.5 to 4.6	V
DC input voltage (OEAB, OEBA, LEAB, LEBA, CKAB, CKBA)	VIN	-0.5 to 4.6	V
DC bus I/O voltage	V _{I/O}	-0.5 to 4.6 (Note 2) -0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	lık	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	₹D.	400	mW
DC V _{CC} /ground current per supply pin	Icc/Ignd	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	1.8 to 3.6	V
Fower supply voltage	VCC.	1.2 to 3.6 (Note 2)	V
Input voltage (OEAB, OEBA, LEAB, LEBA, CKAB, CKBA)	V _{IN}	-0.3 to 3.6	٧ (
Bus I/O voltage	\/ <u>-</u>	0 to 3.6 (Note 3)	V
Bus I/O voltage	V _{I/O}	0 to V _{CC} (Note 4)	('(//
		±12 (Note 5)	
Output current	I _{OH} /I _{OL}	±8 (Note 6)	mA
		±4 (Note 7)	
Operating temperature	T _{opr}	-40 to 85	>°C
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V

- Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.
- Note 2: Data retention only
- Note 3: OFF-state
- Note 4: High or low state
- Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
- Note 6: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
- Note 7: $V_{CC} = 1.8 \text{ V}$
- Note 8: $V_{IN} = 0.8 \text{ to } 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

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Electrical Characteristics

DC Characteristics (Ta = -40 to 85° C, $2.7 \text{ V} < \text{V}_{\text{CC}} \le 3.6 \text{ V})$

Characteris	tics	Symbol	Test Co	ondition	V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	-	_	2.7 to 3.6	2.0	_	V
input voitage	L-level	V _{IL}	-	_	2.7 to 3.6	-	0.8	V
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2		
	H-level	Voh	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -6 mA	//2.7	2.2	_	
				$I_{OH} = -8 \text{ mA}$	3.0	2.4		
Output voltage				$I_{OH} = -12 \text{ mA}$	3.0	2.2		V
			$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \mu\text{A}$	2.7 to 3.6		0.2	
	L-level	V _{OL}		I _{OL} = 6 mA	2.7	#	0.4	
	L-level	VOL		$I_{OL} = 8 \text{ mA}$	3.0	///	0.55	
				I _{OL} ≠ 12 mA	3.0(()	0.8	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		2.7 to 3.6	K)	±5.0	μΑ
3-state output OFF state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		2.7 to 3.6	> _	±10.0	μΑ
Power-off leakage cur	rent	l _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V				10.0	μА
Ouisseent august augrant		Icc	V _{IN} = V _{CC} or GND		2.7 to 3.6	_	20.0	
Quiescent supply cult	Quiescent supply current		V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		2.7 to 3.6	_	±20.0	μΑ
Increase in I _{CC} per in	put	Δl _{CC}	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	750	

DC Characteristics (Ta = -40 to 85° C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteristi	cs	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit	
Input voltage	H-level	V _{IH}			2.3 to 2.7	1.6	_	V	
input voitage	Level	V⊪		<u>) </u>	2.3 to 2.7	_	0.7	V	
		>		I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	_		
	H-level	V _{OH}	VIN = VIH or VIL	$I_{OH} = -4 \text{ mA}$	2.3	2.0	_		
	$\backslash \cap$	0	\sim	$I_{OH} = -6 \text{ mA}$	2.3	1.8	_		
Output voltage		<u></u>		$I_{OH} = -8 \text{ mA}$	2.3	1.7	_	V	
)		ViN = VIH or VIL	$I_{OL} = 100 \mu A$	2.3 to 2.7	_	0.2		
	L-level	VOL		$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 6 mA	2.3	_	0.4	
		2		I _{OL} = 8 mA	2.3	_	0.6		
Input leakage current	4	TIN.	V _{IN} = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μΑ	
3-state output OFF state	e current	loz	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0$ to 3.6 V		2.3 to 2.7	_	±10.0	μА	
Power-off leakage curre	ent	l _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μΑ	
Outroped supply supply			V _{IN} = V _{CC} or GND		2.3 to 2.7	_	20.0	^	
Quiescent supply curre	111	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3$.6 V	2.3 to 2.7	_	±20.0	μА	

DC Characteristics (Ta = -40 to 85°C, 1.8 V \leq V $_{CC}$ < 2.3 V)

Characteristi	cs	Symbol	mbol Test Condition			Min	Max	Unit
		- J			V _{CC} (V)			
Input voltage	H-level	V _{IH}	_	_	1.8 to 2.3	$\begin{array}{c} 0.7 \times \\ V_{CC} \end{array}$		V
input voltage	L-level	VIL	_	_	1.8 to 2.3		$^{0.2\times}_{\text{CC}}$	v
	H-level	Voh	VIN = VIH or VIL	I _{OH} = -100 μA	1.8	VCC - 0.2	_	
Output voltage				I _{OH} = -4 mA	71.8	1.4	_	V
	L-level	\/a.	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	I _{OL} = 100 μA	1.8		0.2	
	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 4 mA	1.8		0.3	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		1.8		±5.0	μΑ
3-state output OFF sta	te current	loz	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0$ to 3.6 V	4	1.8	<u> </u>	±10.0	μА
Power-off leakage curr	ent	loff	V_{IN} , $V_{OUT} = 0$ to 3.6 V		0	7-/	> 10.0	μΑ
Ouissant auguly augrant			V _{IN} = V _{CC} or GND		1.8		20.0	μА
Quiescent supply curre	ant	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3$.6 V	1.8		±20.0	μΑ

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AC Characteristics (Ta = –40 to 85°C, input: $t_r = t_f$ = 2.0 ns, C_L = 30 pF, R_L = 500 Ω) (Note 1)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
			1.8	100	_	
Maximum clock frequency	f _{max}	Figure 1, Figure 3	2.5 ± 0.2	200	_	MHz
			3.3 ± 0.3	250	_	
Propagation delay time	+		1.8	1.5	9.8	
(An, Bn-Bn, An)	t _{pLH} t _{pHL}	Figure 1, Figure 2	2.5 ± 0.2	0.8	4.9	ns
(741, 511 511, 741)	чрпс		3.3 ± 0.3	0.6	3.8	
Propagation delay time	t-111		1.8	1.5	9.8	
(CKAB, CLKBA-Bn, An)	t _{pLH} t _{pHL}	Figure 1, Figure 3	2.5 ± 0.2	0.8	5.8	ns
(010 15, 02115/1 511,711)	чрпс		3.3 ± 0.3	0.6	4.4	
Propagation delay time	t-111	4(>>	1.8	1,5	9.8	
(LEAB, LEBA-Bn, An)	t _{pLH} t _{pHL}	Figure 1, Figure 4	2.5 ± 0.2	0.8	6.3	ns
(CEAS, CESA SII, AII)	чрпс	(\langle / \rangle)	3.3 ± 0.3	0.6	4.7	
Output enable time	t.=0		1.8	4.5	9.8	
(OEAB, OEBA -Bn, An)	t _{pZL} t _{pZH}	Figure 1, Figure 5, Figure 6	2.5 ± 0.2	0.8	5.9	ns
(OLNO, OLDIV BII, MII)		4(>)	3.3 ± 0.3	0.6	4.3	
Output disable time	t _{pLZ}		1.8	1.5	8.8	
(OEAB, OEBA -Bn, An)	t _{pHZ}	Figure 1, Figure 5, Figure 6	2.5 ± 0.2	8.0	4.9	ns
(02713, 0237, 311,711)	ΨΗΖ		3.3 ± 0.3	0.6	4.3	
	haz a n		1.8	4.0	_	
Minimum pulse width	tw (H)	Figure 1, Figure 3, Figure 4	2.5 ± 0.2	1.5	_	ns
	W (L)		3.3 ± 0.3	1.5	_	
			1.8	2.5	_	
Minimum setup time	(t _s)	Figure 1, Figure 3, Figure 4	2.5 ± 0.2	1.5	_	ns
	(\vee)		3.3 ± 0.3	1.5	_	
//)]		$\langle \langle \langle // \rangle \rangle$	1.8	1.0	_	
Minimum hold time	th	Figure 1, Figure 3, Figure 4	2.5 ± 0.2	1.0	_	ns
	>		3.3 ± 0.3	1.0	_	
\sim	t		1.8	_	0.5	
Output to output skew	tosLH	(Note 2)	2.5 ± 0.2	_	0.5	ns
	tosHL		3.3 ± 0.3	_	0.5	

Note 1: For C_L = 50 pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: t_r = t_f = 2.0 ns, C_L = 30 pF, R_L = 500 Ω)

Characteristics	Symbol	Test Condition VCC (V)		Тур.	Unit	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	0.15	
Quiet output maximum dynamic V _{OI}	V _{OLP}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	0.25	V
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	0.35	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	-0.15	
Quiet output minimum dynamic V _{OI}	V _{OLV}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	-0.25	V
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	-0.35	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	1.55	
Quiet output minimum dynamic V _{OH}	V _{OHV}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	2.05	V
TY TOTAL		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	2.65	

Parameter guaranteed by design. Note:

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}		(/ /)	1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}			1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note)	1.8, 2.5, 3.3	20	pF

CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating Note: current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/18 \text{ (per bit)}$



AC Test Circuit

Output (Bn, An)

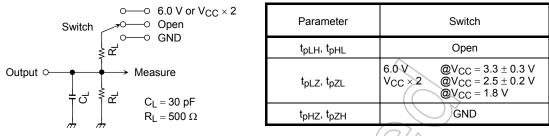


Figure 1 **AC Waveform** t_f 2.0 ns t_{Γ} 2.0 ns Уιн Input VM (An, Bn) GND Voh Output V_{M} (Bn, An) V_{OL} t_{pLH} tpHL Figure 2 tpLH, tpHL t_r 2.0 ns t_f 2.0 ns · V_{IH} 90% Input (CKAB, CKBA) GND $t_{w}(H)$ $t_{W}(L)$ V_{IH} Input (An, Bn) GND t_s (H) $t_h(H)$ ts (L) t_h (L)

Figure 3 $t_{pLH}, t_{pHL}, t_w, t_s, t_h$

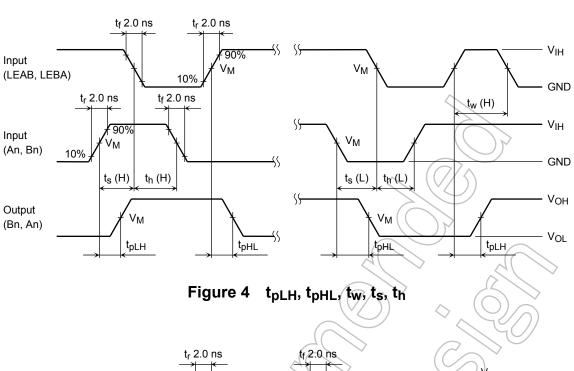
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tpLH

t_{pHL}

- V_{OH}

- V_{OL}



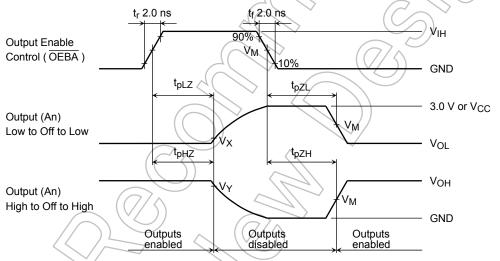


Figure 5 t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}

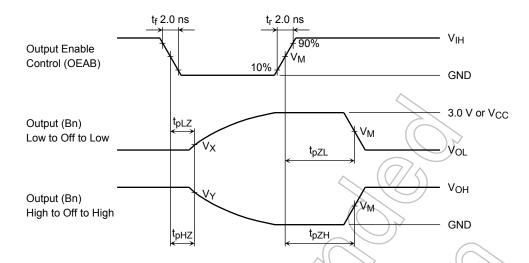
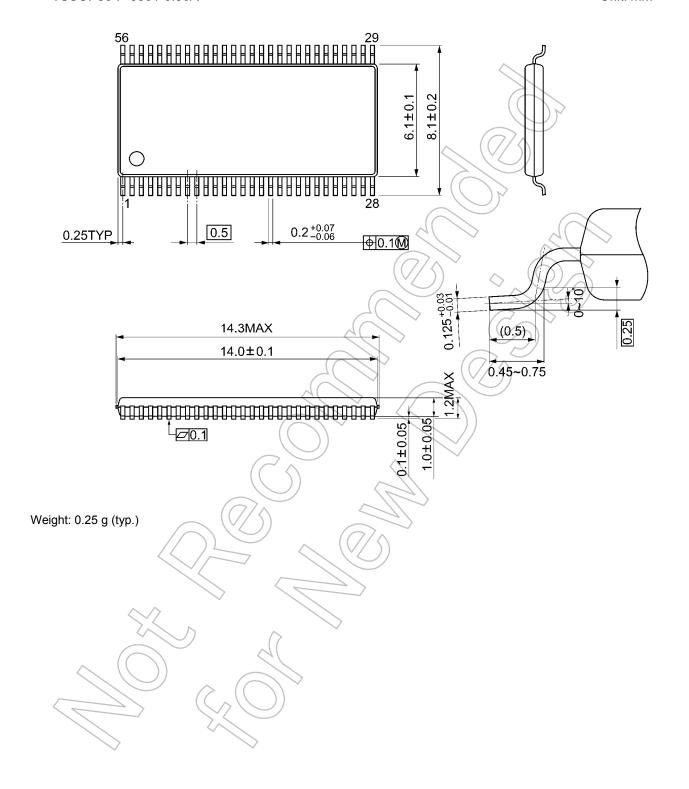


Figure 6 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Symbol		Vec	
Symbol	$3.3\pm0.3~\textrm{V}$	2.5 ± 0.2 V	1.8 V
V_{IH}	2.7 V	V _{CC}	Vcc
V _M	1.5 V	V _{CC} /2	Vcc/2
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V

Package Dimensions

TSSOP56-P-0061-0.50A Unit: mm



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